











SN74LVC2G06

SCES307J-AUGUST 2001-REVISED JULY 2015

SN74LVC2G06 Dual Inverter Buffer and Driver With Open-Drain Outputs

Features

- Available in the Texas Instruments Package
- Supports 5-V V_{CC} Operation
- Max t_{pd} of 3.4 ns at 3.3 V
- Low Power Consumption, 10- μ A Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at V_{CC} = 3.3 V, T_A = 25°C
- Inputs and Open-Drain Outputs Accept Voltages up to 5.5 V
- I_{off} Supports Live Insertion, Partial-Power-Down Mode and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Supports Down-Translation (5 V to 3.3 V and 3.3 V to 1.8 V)
- ESD Protection Exceeds JESD 22
 - 2000-V Human Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- **AV Receivers**
- Blu-ray Players and Home Theaters
- **DVD Recorders and Players**
- Desktop or Notebook PCs
- Digital Radio or Internet Radio Players
- Digital Video Cameras (DVC)
- Embedded PC
- **GPS: Personal Navigation Devices**
- Mobile Internet Devices
- Network Projector Front-End
- Portable Media Players
- Pro Audio Mixers
- **Smoke Detectors**
- Solid-State Drive (SSD): Enterprise
- High-Definition (HDTV)

3 Description

This dual inverter buffer and driver is designed for 1.65-V to 5.5-V V_{CC} operation.

The output of the SN74LVC2G06 device is an opendrain which can be connected to other open-drain outputs to implement active-low, wired-OR, or activehigh wired-AND functions. The maximum sink current is 32 mA.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

Device Information⁽¹⁾

| ORDER NUMBER | PACKAGE | BODY SIZE (NOM) |
|----------------|------------|-------------------|
| SN74LVC2G06DBV | SOT-23 (6) | 2.90 mm × 1.60 mm |
| SN74LVC2G06DCK | SC70 (6) | 2.00 mm × 1.25 mm |
| SN74LVC2G06DRY | SON (6) | 1.45 mm × 1.00 mm |
| SN74LVC2G06DSF | SON (6) | 1.00 mm × 1.00 mm |
| SN74LVC2G06YZP | DSBGA (6) | 1.41 mm × 0.91 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram

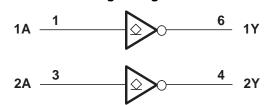




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision I (December 2013) to Revision J

Page

Changes from Revision H (August 2012) to Revision I

Page

| • | Updated document to new TI data sheet format. | . 1 |
|---|---|-----|
| • | Removed Ordering Information table. | . 1 |
| • | Added ESD warning | 1 |
| • | Updated operating temperature range. | 5 |

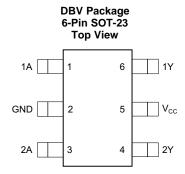
Changes from Revision G (January 2007) to Revision H

Page

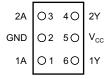
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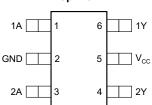
5 Pin Configuration and Functions



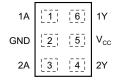




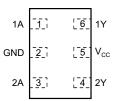




DRY Package 6-Pin SON Top View



DSF Package 6-Pin SON Top View



Pin Functions

| P | IN | I/O | DESCRIPTION |
|-----------------|----|-----|---------------------|
| NAME | NO | 1/0 | DESCRIPTION |
| GND | 2 | _ | Ground |
| 1A | 1 | I | Input 1 |
| 2A | 3 | I | Input 2 |
| 1Y | 6 | I | Open-drain output 1 |
| 2Y | 4 | 0 | Open-drain output 2 |
| V _{CC} | 5 | _ | Power pin |

Product Folder Links: SN74LVC2G06



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|---|-------------------------------|------|------|------|
| V_{CC} | Supply voltage | | -0.5 | 6.5 | V |
| VI | Input voltage (2) | | -0.5 | 6.5 | V |
| Vo | Voltage applied to any output in the high-impedance or po | ower-off state ⁽²⁾ | -0.5 | 6.5 | V |
| Vo | Voltage applied to any output in the high or low state (2)(3) | | -0.5 | 6.5 | V |
| I _{IK} | Input clamp current | V _I < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| Io | Continuous output current | | | ±50 | mA |
| | Continuous current through V _{CC} or GND | | | ±100 | mA |
| T _{stg} | Storage Temperature | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| | | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | +2000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | +1000 | V |

1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the *Recommended Operating Conditions* table.



6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

| | | | MIN | NOM MAX | UNIT |
|-----------------|------------------------------------|---|-----------------------|------------------------|------|
| ., | Owner by continue | Operating | 1.65 | 5.5 | ., |
| V _{CC} | Supply voltage | Data retention only | 1.5 | | V |
| | | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | | |
| ., | I Park Town County and to an | V _{CC} = 2.3 V to 2.7 V | 1.7 | | ., |
| V_{IH} | High-level input voltage | V _{CC} = 3 V to 3.6 V | 2 | | V |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7 × V _{CC} | | |
| | | V _{CC} = 1.65 V to 1.95 V | | 0.35 × V _{CC} | |
| ., | Landard Construction | V _{CC} = 2.3 V to 2.7 V | | 0.7 | V |
| V_{IL} | Low-level input voltage | V _{CC} = 3 V to 3.6 V | | 0.8 | V |
| | | V _{CC} = 4.5 V to 5.5 V | | 0.3 × V _{CC} | |
| VI | Input voltage | | 0 | 5.5 | V |
| Vo | Output voltage | | 0 | 5.5 | V |
| | | V _{CC} = 1.65 V | | 4 | |
| | | V _{CC} = 2.3 V | | 8 | |
| I_{OL} | Low-level output current | v 2V | | 16 | mA |
| | | V _{CC} = 3 V | | 24 | |
| | | V _{CC} = 4.5 V | | 32 | |
| | | V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | | 20 | |
| Δt/Δν | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | 10 | ns/V |
| | | V _{CC} = 5 V ± 0.5 V | | 5 | |
| T _A | Operating free-air temperature | | -40 | 125 | °C |

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

6.4 Thermal Information

| | | | | SN74LVC2G06 | | | |
|-------------------------------|--|------------------|------------|-------------|-------------|-----------|------|
| THERMAL METRIC ⁽¹⁾ | | DBV (SOT- 23) | DCK (SC70) | DRY (SON) | YPZ (DSBGA) | DSF (SON) | UNIT |
| | | 6 PINS | 6 PINS | 6 PINS | 6 PINS | 6 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 165 | 259 | 234 | 123 | 300 | °C/W |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: SN74LVC2G06



6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| DADA | METER | TEST SOMBITIONS | v | -40°C to 85°C | -40°C to 125°C | LINUT | |
|----------------------------------|-------------------------|---|-------------------------|----------------------------|----------------------------|-------|--|
| PARAMETER | | TEST CONDITIONS | V _{cc} | MIN TYP ⁽¹⁾ MAX | MIN TYP ⁽¹⁾ MAX | UNIT | |
| | | I _{OL} = 100 μA | 1.65 V to 5.5 V | 0.1 | 0.1 | | |
| | | I _{OL} = 4 mA | 1.65 V | 0.45 | 0.45 | | |
| V _{OL} | | I _{OL} = 8 mA | 2.3 V | 0.3 | 0.3 | V | |
| | I _{OL} = 16 mA | | I _{OL} = 16 mA | | 3 V | 0.4 | |
| | | I _{OL} = 24 mA | 3 V | 0.55 | 0.55 | | |
| | | I _{OL} = 32 mA | 4.5 V | 0.55 | 0.55 | | |
| I _I | A inputs | V _I = 5.5 V or GND | 0 to 5.5 V | ±5 | ±5 | μΑ | |
| I _{off} | | V_I or $V_O = 5.5 V$ | 0 | ±10 | ±10 | μΑ | |
| I _{CC} ΔI _{CC} | | $V_I = 5.5 \text{ V or GND}, \qquad I_O = 0$ | 1.65 V to 5.5 V | 10 | 10 | μΑ | |
| | | One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND | 3 V to 5.5 V | 500 | 500 | μΑ | |
| C _i | · | $V_I = V_{CC}$ or GND | 3.3 V | 3.5 | 3.5 | pF | |

⁽¹⁾ All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

6.6 Switching Characteristics for -40°C to 85°C

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = ± 0.1 | | V _{CC} = ± 0.2 | | V _{CC} = ± 0.3 | | V _{CC} = ± 0. | | UNIT |
|-----------------|-----------------|----------------|-------------------------|-----|----------------------------|-----|-------------------------|-----|------------------------|-----|------|
| | (INFOT) | (001701) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | Α | Υ | 1.8 | 7.2 | 1 | 3.9 | 1 | 3.4 | 1 | 2.9 | ns |

6.7 Switching Characteristics for -40°C to 125°C

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 1.8 V ± 0.15 V | | V _{CC} = 2.5 V ± 0.2 V | | V _{CC} = 3.3 V ± 0.3 V | | V _{CC} = 5 V ± 0.5 V | | UNIT |
|-----------|-----------------|-------------|-------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|
| | (INPUT) | (OUTPUT) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t_{pd} | Α | Υ | 1.8 | 8.2 | 1 | 4.4 | 1 | 3.9 | 1 | 3.4 | ns |

6.8 Operating Characteristics

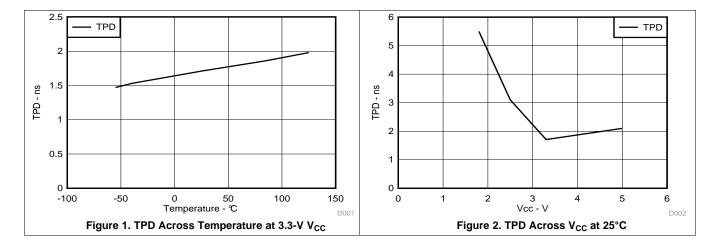
 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | V _{CC} = 1.8 V | V _{CC} = 2.5 V | V _{CC} = 3.3 V | V _{CC} = 5 V | UNIT |
|----------|-------------------------------|-----------------|-------------------------|-------------------------|-------------------------|-----------------------|------|
| | PARAMETER | TEST CONDITIONS | TYP | TYP | TYP | TYP | UNII |
| C_{pd} | Power dissipation capacitance | f = 10 MHz | 2 | 2 | 3 | 4 | pF |

Product Folder Links: SN74LVC2G06



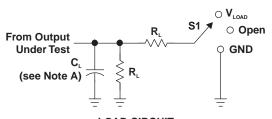
6.9 Typical Characteristics



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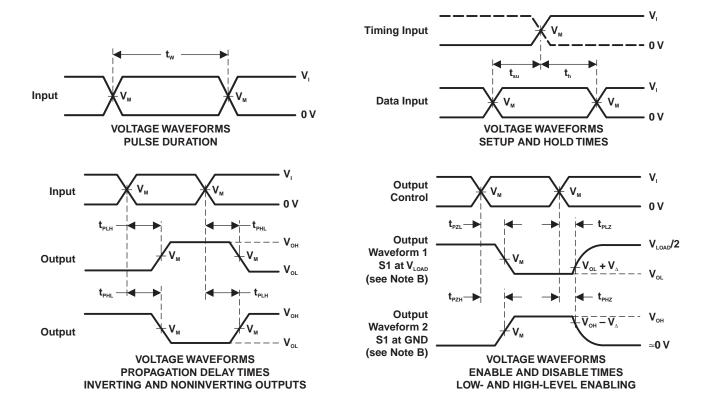
7 Parameter Measurement Information



| TEST | S1 |
|--------------------------------------|--------------------------|
| t _{PZL} (see Notes E and F) | V _{LOAD} |
| t _{PLZ} (see Notes E and G) | V _{LOAD} |
| t _{PHZ} /t _{PZH} | V _{LOAD} |

| ı | LC |)A | D | CI | R | C | U | Т |
|---|----|----|---|----|---|---|---|---|
| | | | | | | | | |

| ., | INI | PUTS | ., | ., | | _ | ., | |
|-------------------------------------|-----------------|---------------|--------------------|---------------------|----------------|----------------|----------------|---|
| V _{cc} | V, | t,/t, | V _M | V _{LOAD} | C _∟ | R _⊾ | V _A | |
| 1.8 V \pm 0.15 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 1 k Ω | 0.15 V | |
| $\textbf{2.5 V} \pm \textbf{0.2 V}$ | V _{cc} | ≤ 2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 500 Ω | 0.15 V | l |
| 3.3 V \pm 0.3 V | 3 V | ≤2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V | l |
| 5 V \pm 0.5 V | V _{cc} | ≤2.5 ns | V _{cc} /2 | 2 × V _{cc} | 50 pF | 500 Ω | 0.3 V | |



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators have the following characteristics: PRR \leq 10 MHz, Z_{o} = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. Because this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{PD} .
- F. $t_{\tiny PZL}$ is measured at $V_{\tiny M}$.
- G. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms (Open Drain)

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8 Detailed Description

8.1 Overview

The SN74LVC2G06 dual open-drain inverter device contains one open-drain inverter with a maximum sink current of 32 mA. This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram



8.3 Feature Description

The wide operating voltage range of 1.65 V to 5.5 V allows the SN74LVC2G06 to be used in systems with many different voltage rails. In addition, the voltage tolerance on the output allows the device to be used for inverting up-translation or down-translation. The I_{OFF} feature safely allows voltage on the inputs and outputs when there's no V_{CC} is present.

8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74LVC2G06.

Table 1. Function Table

| INPUT A | OUTPUT Y |
|------------|-------------|
| L | Hi-Z |
| Н | L |

Product Folder Links: SN74LVC2G06



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74LVC2G06 is a dual high-drive CMOS device that implements a high-output drive buffer, such as an LED application. This device can sink 32 mA of current at 4.5 V making it ideal for high-drive applications and high-speed applications up to 100 MHz. The inputs are 5.5-V tolerant and let it to translate up or down to V_{CC} . The following *Typical Application* shows a simple LED driver application for a single channel of the device.

9.2 Typical Application

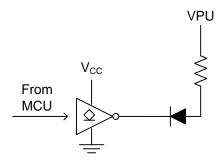


Figure 4. Typical Application Diagram

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Avoid bus contention because it can drive currents that exceed maximum limits. The high drive also creates fast edges into light loads. Consider routing and load conditions to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs. See $(\Delta t/\Delta V)$ in the *Recommended Operating Conditions* table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the Recommended Operating
 Conditions table at any valid V_{CC}.

2. Recommend Output Conditions

- Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in *Absolute Maximum Ratings* table.
- Do not pull outputs above 5.5 V.

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Typical Application (continued)

9.2.3 Application Curve

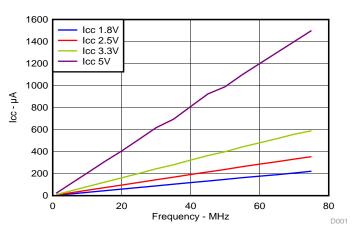


Figure 5. I_{CC} vs Frequency

10 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin must have a good bypass capacitor in order to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended and if there are multiple V_{CC} pins then a 0.01- μ F or 0.022- μ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs must never float. In many cases, functions or parts of functions of digital logic devices are unused. Examples include when only two inputs of a triple input and gate are used or when only three of the four buffer gates are used. Avoid leaving input pins unconnected because the undefined voltages at the outside connections result in undefined operational states. Observe the following rules under all circumstances. Connect all unused inputs of digital logic devices to a high or low bias to prevent them from floating. Based on the function of the device, apply the logic level to any unused input. Based on convenience, tie unused inputs to the GND or the $V_{\rm CC}$.

11.2 Layout Example



Figure 6. Layout Recommendation

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12 Device and Documentation Support

12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.2 Trademarks

NanoFree, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC2G06

www.ti.com

7-Oct-2025

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|------------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| SN74LVC2G06DBVR | Active | Production | SOT-23 (DBV) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (C065, C06R) |
| SN74LVC2G06DBVR.B | Active | Production | SOT-23 (DBV) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (C065, C06R) |
| SN74LVC2G06DBVRE4 | Active | Production | SOT-23 (DBV) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (C065, C06R) |
| SN74LVC2G06DCKR | Active | Production | SC70 (DCK) 6 | 3000 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | (CT5, CTJ, CTR) |
| SN74LVC2G06DCKR.B | Active | Production | SC70 (DCK) 6 | 3000 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | (CT5, CTJ, CTR) |
| SN74LVC2G06DCKRE4 | Active | Production | SC70 (DCK) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT5 |
| SN74LVC2G06DCKRG4 | Active | Production | SC70 (DCK) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT5 |
| SN74LVC2G06DCKRG4.B | Active | Production | SC70 (DCK) 6 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT5 |
| SN74LVC2G06DRYR | Active | Production | SON (DRY) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | СТ |
| SN74LVC2G06DRYR.B | Active | Production | SON (DRY) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | СТ |
| SN74LVC2G06DRYRG4 | Active | Production | SON (DRY) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | СТ |
| SN74LVC2G06DRYRG4.B | Active | Production | SON (DRY) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | СТ |
| SN74LVC2G06DSFR | Active | Production | SON (DSF) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | СТ |
| SN74LVC2G06DSFR.B | Active | Production | SON (DSF) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT |
| SN74LVC2G06DSFRG4 | Active | Production | SON (DSF) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT |
| SN74LVC2G06DSFRG4.B | Active | Production | SON (DSF) 6 | 5000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CT |
| SN74LVC2G06YZPR | Active | Production | DSBGA (YZP) 6 | 3000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (CT7, CTN) |
| SN74LVC2G06YZPR.B | Active | Production | DSBGA (YZP) 6 | 3000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (CT7, CTN) |

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LVC2G06:

Automotive: SN74LVC2G06-Q1

Enhanced Product : SN74LVC2G06-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LVC2G06DBVR | SOT-23 | DBV | 6 | 3000 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LVC2G06DBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC2G06DCKR | SC70 | DCK | 6 | 3000 | 178.0 | 8.4 | 2.25 | 2.45 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC2G06DCKR | SC70 | DCK | 6 | 3000 | 180.0 | 8.4 | 2.3 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC2G06DCKRG4 | SC70 | DCK | 6 | 3000 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC2G06DRYR | SON | DRY | 6 | 5000 | 180.0 | 9.5 | 1.15 | 1.6 | 0.75 | 4.0 | 8.0 | Q1 |
| SN74LVC2G06DRYRG4 | SON | DRY | 6 | 5000 | 180.0 | 9.5 | 1.15 | 1.6 | 0.75 | 4.0 | 8.0 | Q1 |
| SN74LVC2G06DSFR | SON | DSF | 6 | 5000 | 180.0 | 9.5 | 1.16 | 1.16 | 0.5 | 4.0 | 8.0 | Q2 |
| SN74LVC2G06DSFRG4 | SON | DSF | 6 | 5000 | 180.0 | 9.5 | 1.16 | 1.16 | 0.5 | 4.0 | 8.0 | Q2 |
| SN74LVC2G06YZPR | DSBGA | YZP | 6 | 3000 | 178.0 | 9.2 | 1.02 | 1.52 | 0.63 | 4.0 | 8.0 | Q1 |



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*All dimensions are nominal

| 7 111 01111011010110 0110 11011111101 | | | | | | | |
|---------------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| SN74LVC2G06DBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC2G06DBVR | SOT-23 | DBV | 6 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LVC2G06DCKR | SC70 | DCK | 6 | 3000 | 208.0 | 191.0 | 35.0 |
| SN74LVC2G06DCKR | SC70 | DCK | 6 | 3000 | 210.0 | 185.0 | 35.0 |
| SN74LVC2G06DCKRG4 | SC70 | DCK | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC2G06DRYR | SON | DRY | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC2G06DRYRG4 | SON | DRY | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC2G06DSFR | SON | DSF | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC2G06DSFRG4 | SON | DSF | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC2G06YZPR | DSBGA | YZP | 6 | 3000 | 220.0 | 220.0 | 35.0 |





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





DIE SIZE BALL GRID ARRAY



NOTES:

NanoFree Is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
 For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

 4. Falls within JEDEC MO-203 variation AB.





NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.









NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.





NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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